

# **HL6340MG/41MG**

## Circular Beam Low Operating Current

ODE-208-035A (Z) Rev.1 Feb. 01, 2008

#### **Description**

The HL6340MG/41MG are  $0.63~\mu m$  band AlGaInP laser diodes can be operated with low operating current. These products were designed by self aligned refractive index (SRI) active layer structure. These are suitable as a light source for laser levelers, laser scanners and optical equipment for measurement.

#### **Features**

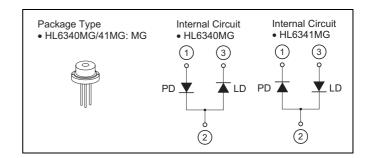
• Optical output power: 5 mW CW

Single longitudinal mode

Visible light power: 635 nm TypLow operating current: 25 mA Typ

Low aspect ratio: 1.2 Typ
Operating temperature: +50°C

• TM mode oscillation



## **Absolute Maximum Ratings**

 $(T_C = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Optical output power	Po	5	mW
Pulse optical output power	P <sub>O(pulse)</sub>	6 *	mW
LD reverse voltage	$V_{R(LD)}$	2	V
PD reverse voltage	$V_{R(PD)}$	30	V
Operating temperature	Topr	-10 to +50	°C
Storage temperature	Tstg	-40 to +85	°C

Note: Pulse condition : Pulse width  $\leq 1 \ \mu s$  , duty  $\leq 50\%$ 

#### **Optical and Electrical Characteristics**

 $(T_C = 25^{\circ}C)$ 

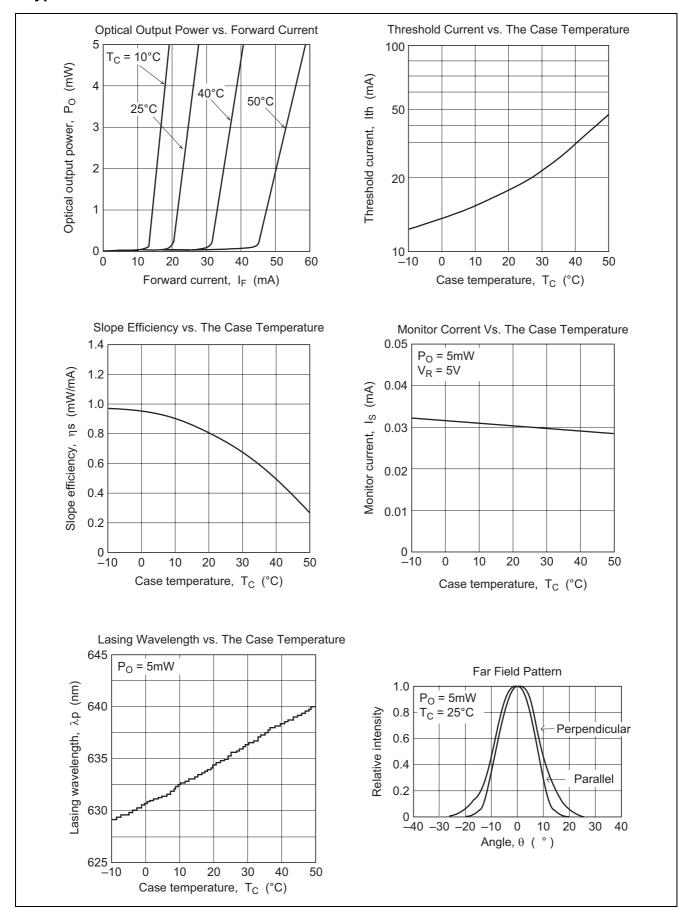
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Threshold current	lth	_	20	30	mA	_
Slope efficiency	ηѕ	0.5	0.8	1.1	mW/mA	3 (mW) / (I <sub>(4mW)</sub> – I <sub>(1mW)</sub> )
Operating current	I <sub>OP</sub>	_	25	40	mA	$P_0 = 5 \text{ mW}$
Operating voltage	V <sub>OP</sub>		2.4	2.7	V	$P_0 = 5 \text{ mW}$
Lasing wavelength	λр	630	635	640	nm	$P_0 = 5 \text{ mW}$
Beam divergence parallel to the junction	θ//	13	17	25	0	$P_0 = 5 \text{ mW}$
Beam divergence perpendicular to the junction	θΤ	16	20	25	0	$P_O = 5 \text{ mW}$
Aspect ratio	θ⊥/θ//	_	1.2	1.5	_	$P_O = 5 \text{ mW}$
Monitor current	Is	0.01	0.03	0.06	mA	$P_0 = 5 \text{ mW}, V_{R(PD)} = 5 \text{ V}$

Notes: 1. Care must be taken in laser diodes handling to prevent optical damage caused by forward surges as well as by ESD.

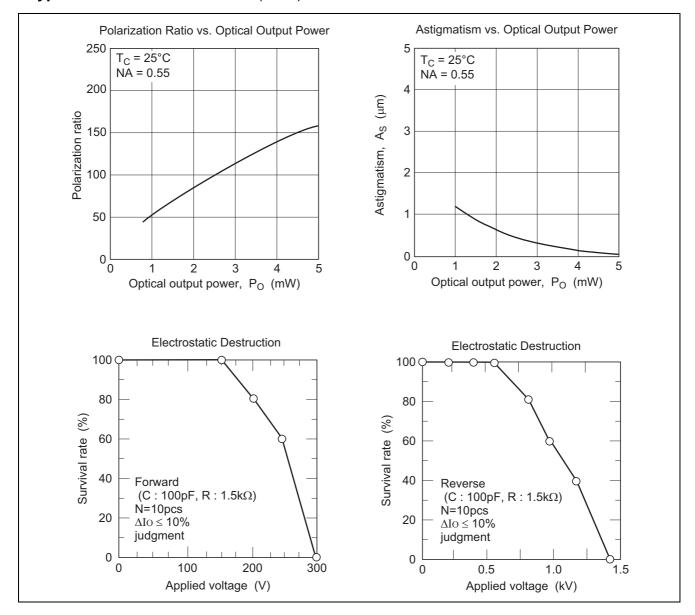
2. The beam has 12 deg offset against the package reference plane. Please take account it mounted on a board.



## **Typical Characteristic Curves**



## Typical Characteristic Curves (cont.)

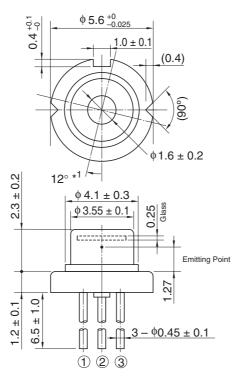


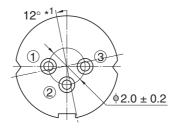
<u>opnext</u>

## **Package Dimensions**

Unit: mm







Note: 1. The beam has 12 deg offset against the package reference plane. Please take account it mounted on a board.

OPJ Code	LD/MG
JEDEC	_
JEITA	_
Mass (reference value)	0.3 g

#### **Cautions**

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#### **Sales Offices**



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